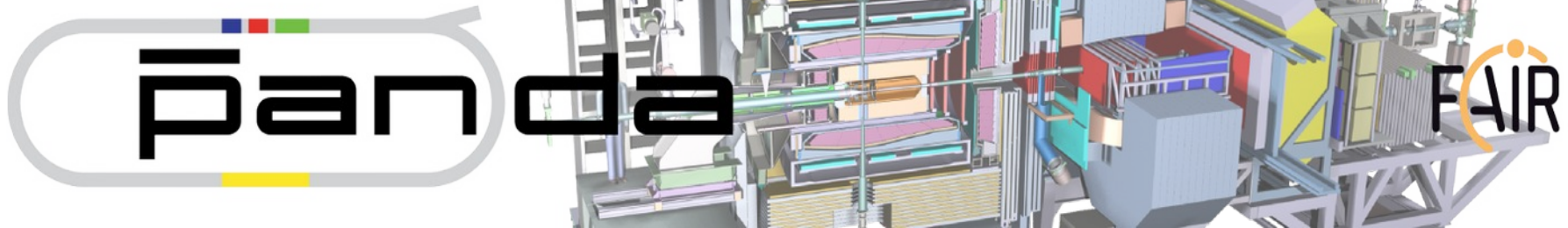


Status Barrel EMC

of the



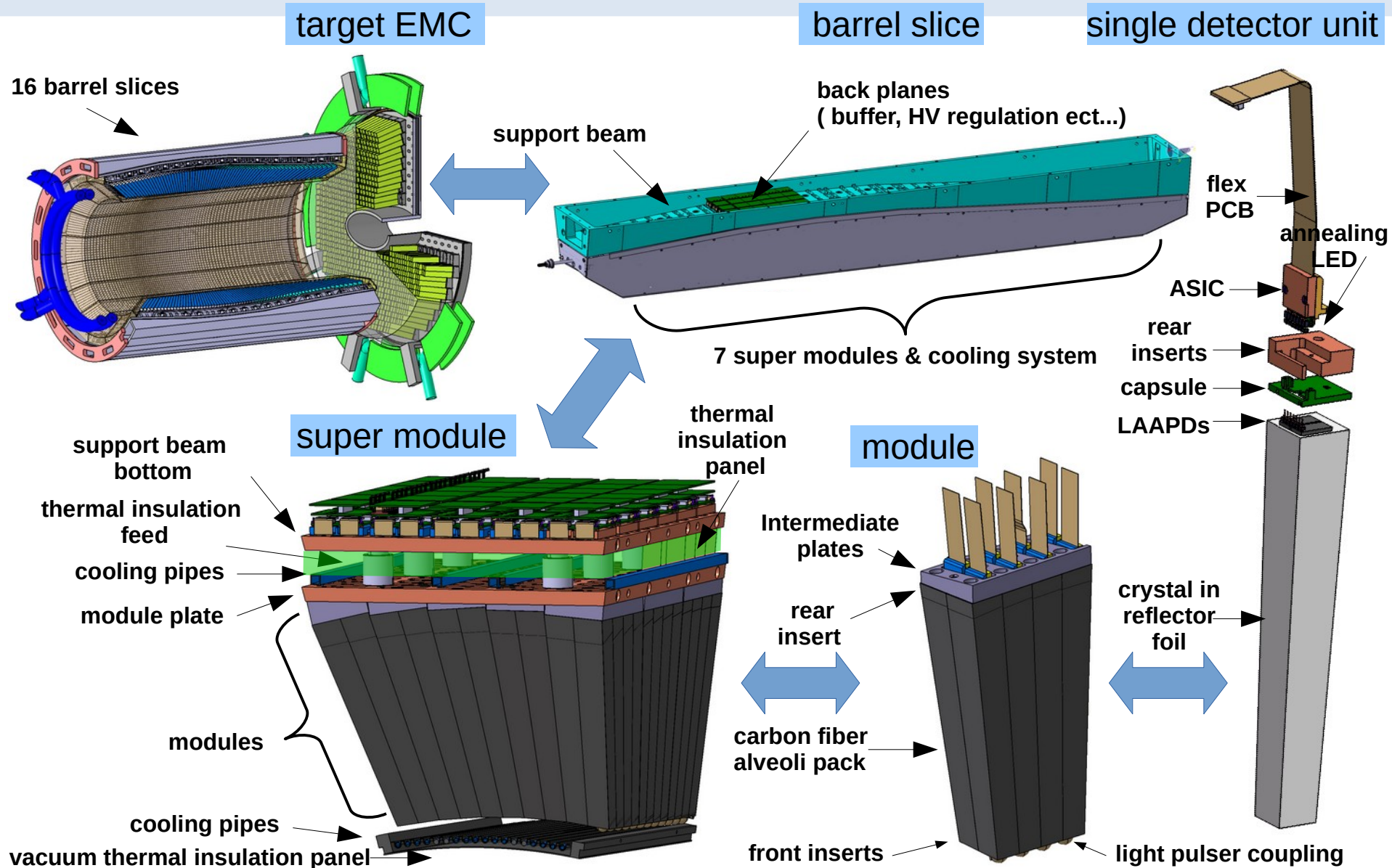
Target Spectrometer

Markus W. H. Moritz

2nd Physics Institute, Giessen University, Germany

PANDA CM, October 2020

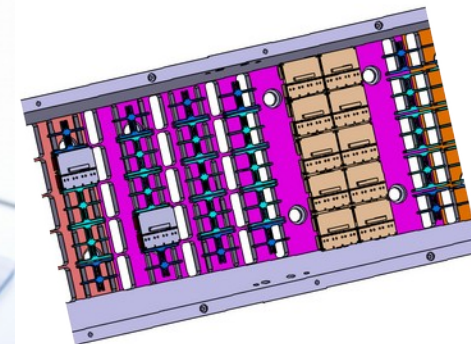
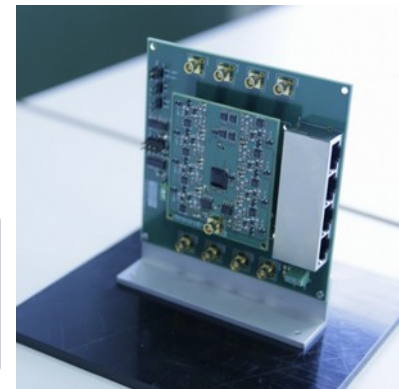
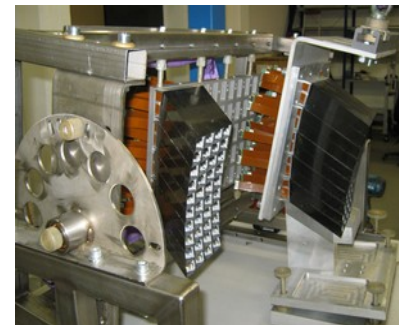
Barrel Calorimeter of the PANDA Target Spectrometer

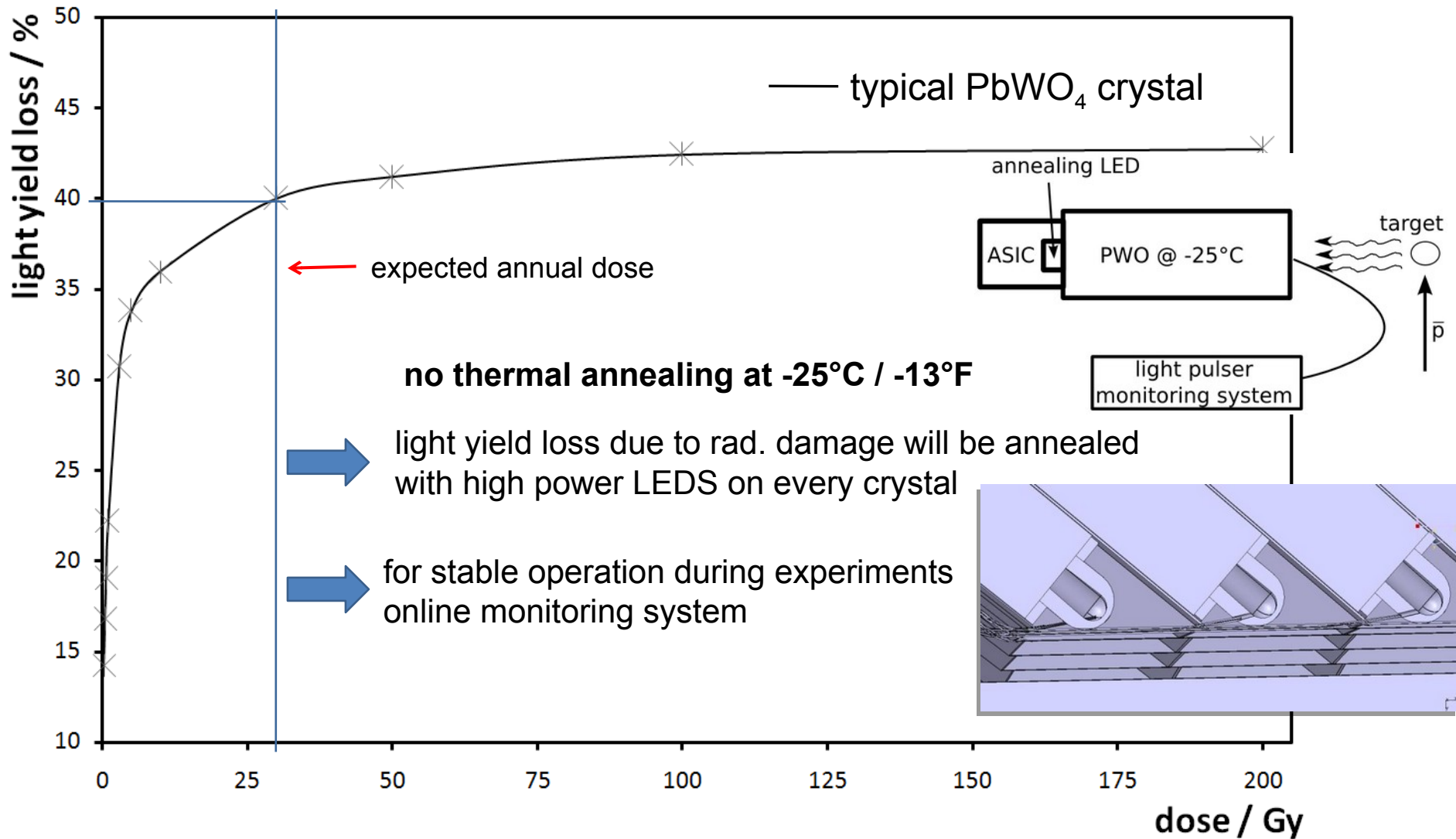


Envisaged milestone (M8): Assembly of 1st full Barrel EMC slice

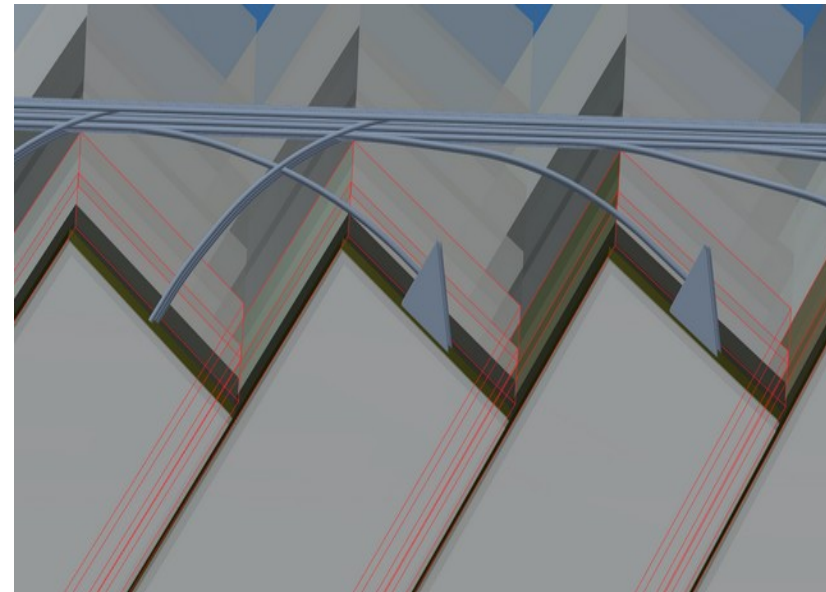
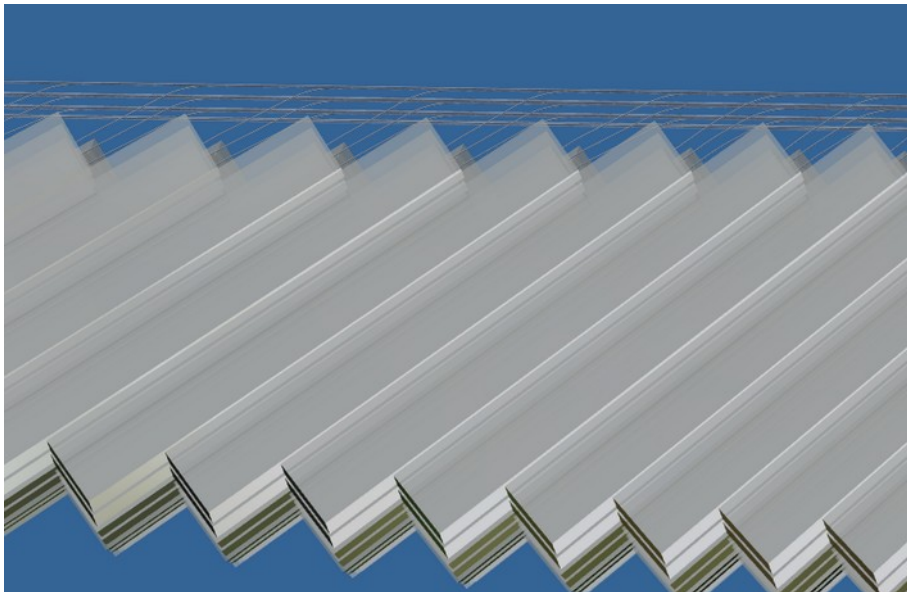
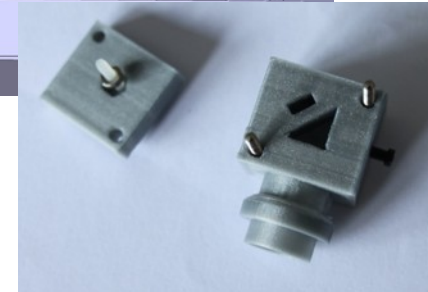
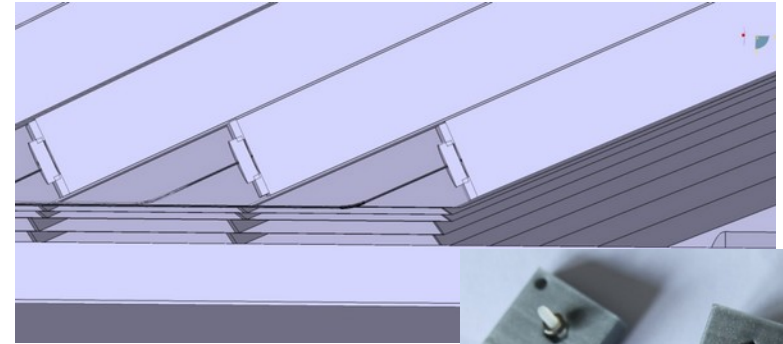
- Infrastructure ✓
- Mechanics ✓
- 710 detectors ✓
 - 710 crystals in 11 different geometries ✓
 - 1420 APDS
 - Screening including irradiation ✓
 - Matching ✓
 - Glueing ✓
- Capsules ✓
- Wrapping ✓
- Assembly of 18 modules ✓
- Assembly of Supermodules ✓
 - 360 left and 360 right handed APFEL-ASIC with flex PCBs ✓
 - ASIC housing or fixtures ✓
- Assembly of full 1st slice X
 - (Re-)design supportbeam ✓
 - Mod. preseries supportbeam
 - Cooling & thermal insulation
 - Backplanes
 - Light pulser fiber coupling

CAD ready
in progress
in progress
in progress



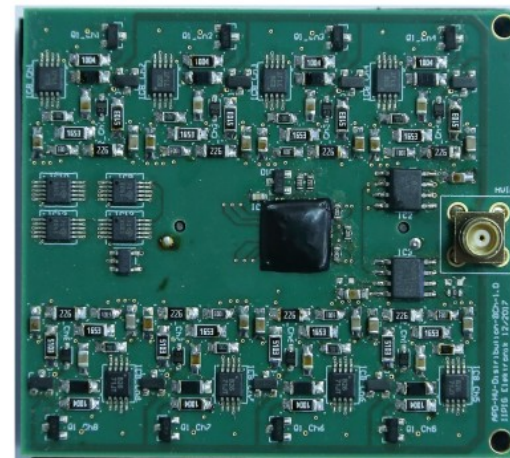
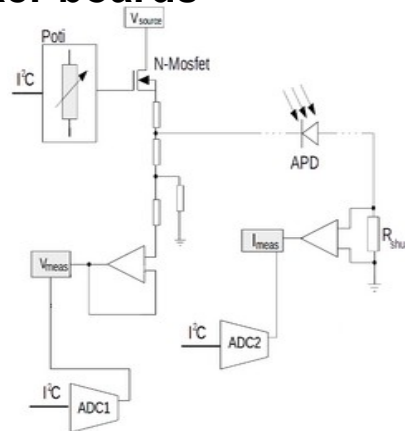
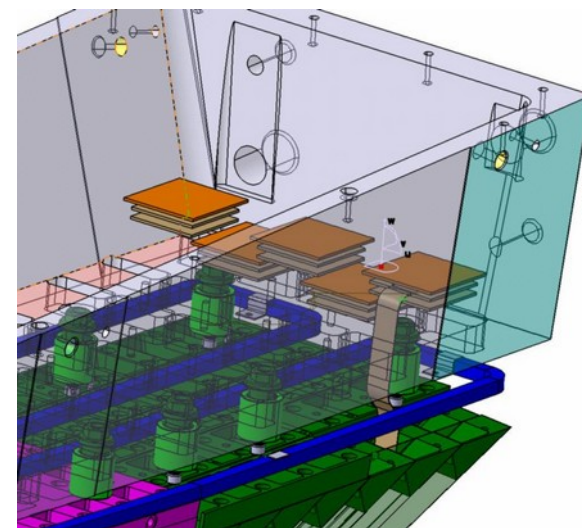


- Space very limited
- Fiber long term bending radius: 33 mm
- Idea: route fibers from up and downstream
 - Advantage:
 - More fibers can directly coupled
 - Rest (39X10) with 90° prism
 - Disadvantage:
 - 1€/m of single fiber



3 Layers

- **Top: HVD board**
 - Adjust bias voltage of 8 APDs
 - 50V from HV input downwards in $< 0,1V$ steps
 - All channels fed from the same HV source
→ safes space inside support beam
 - Online measurement of APD voltage and current
- **Middle: Connector board to multiplexer boards**
- **Bottom: Board for FlexPCBs / ASICs**
 - Connectors to FEs
 - 8x2 Diff. Line drivers
 - APFEL I/F buffers
 - Temp/Humidity sensors
 - HitDetection ASIC



HVD board

3 Layers

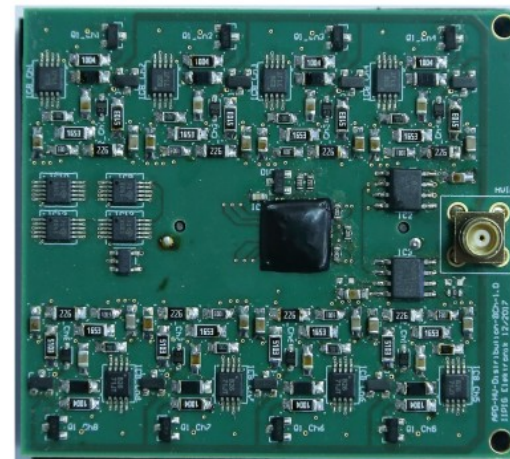
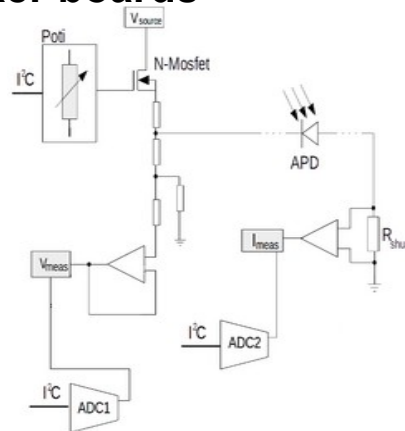
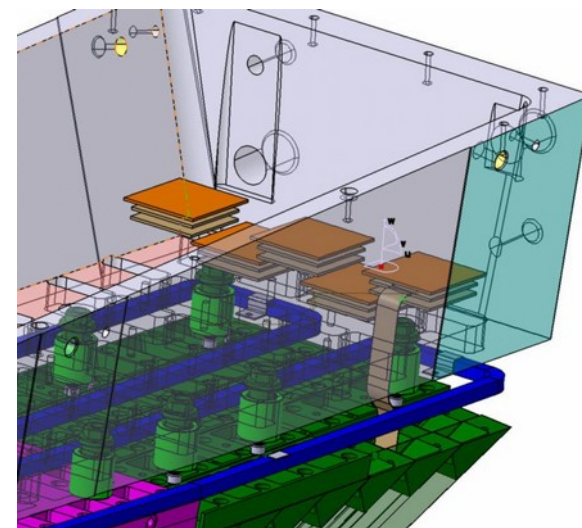
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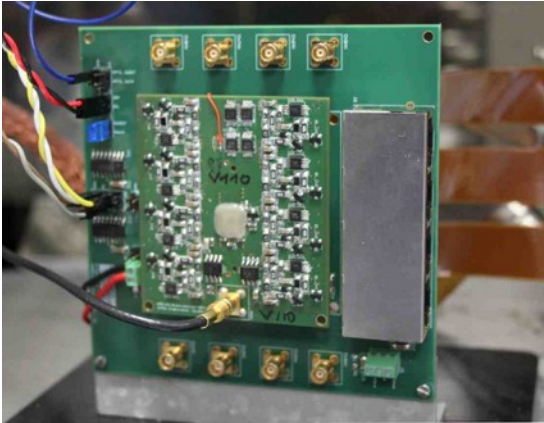
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- 8x2 Diff. Line drivers
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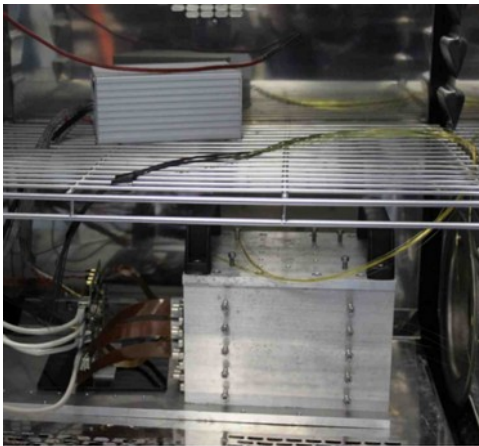


HVD board

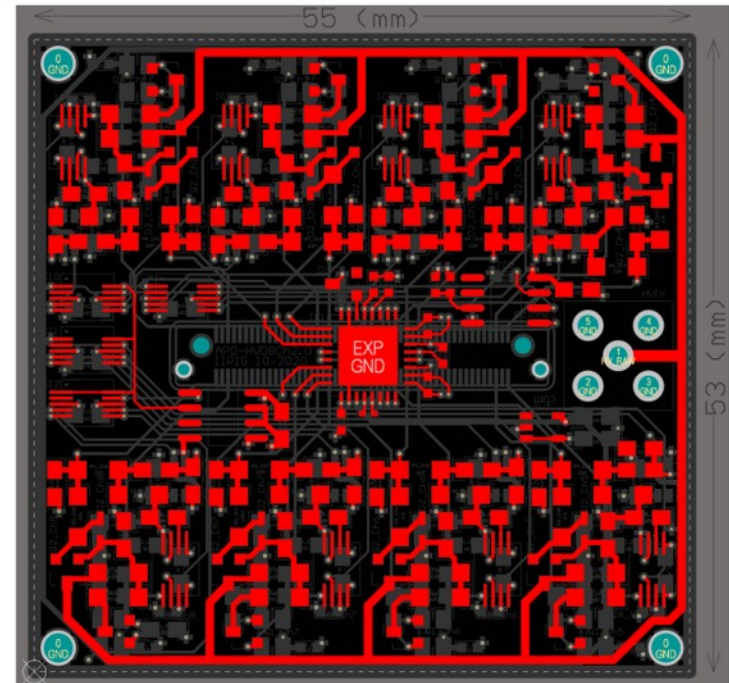
HVD test-board for full functionality tests before mass production



full triple sandwich tests with crystal matrix



Final prototype is currently in production

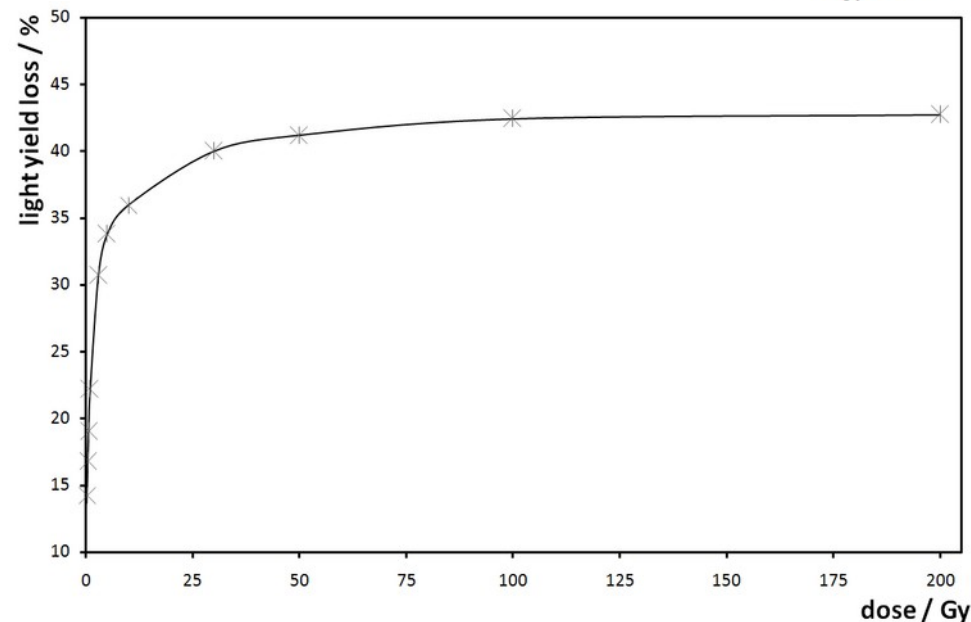
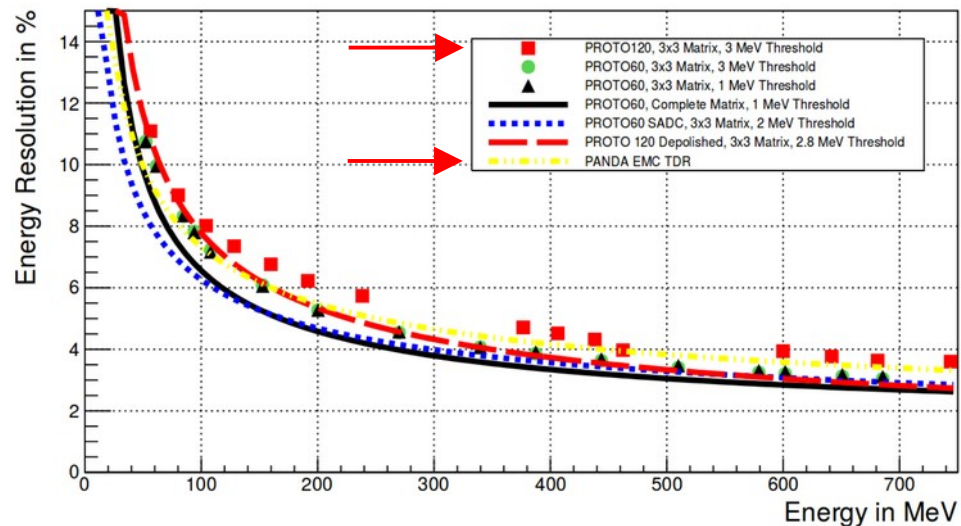


minor changes to the highvoltage regulation part and a decrease in size

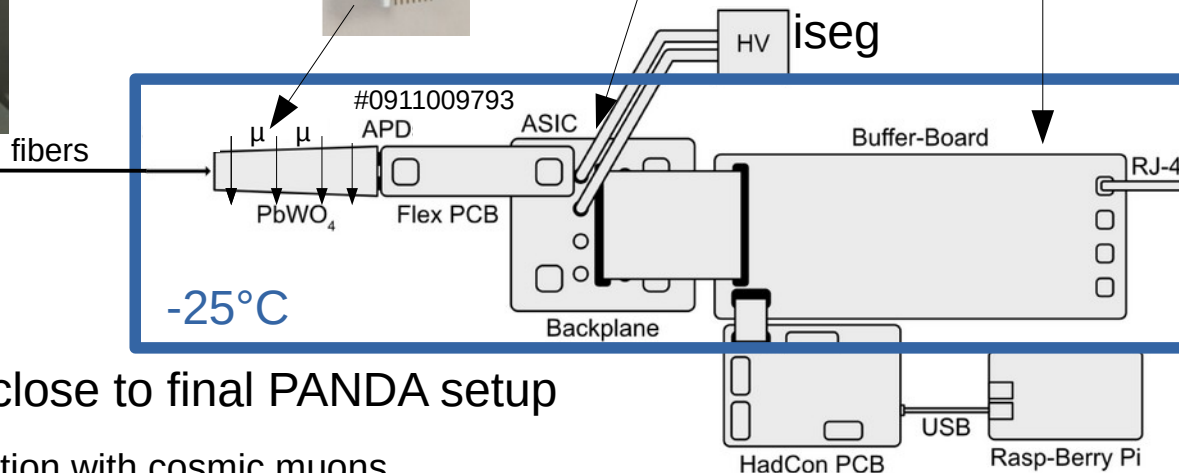
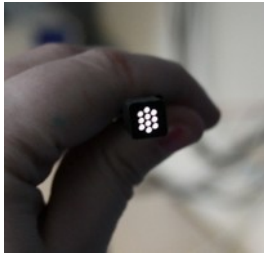
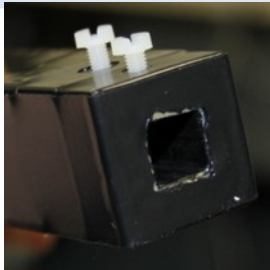
Motivation

TDR resolution goal barely reached especially at low energies

Fast light yield loss within first few gray



Setup

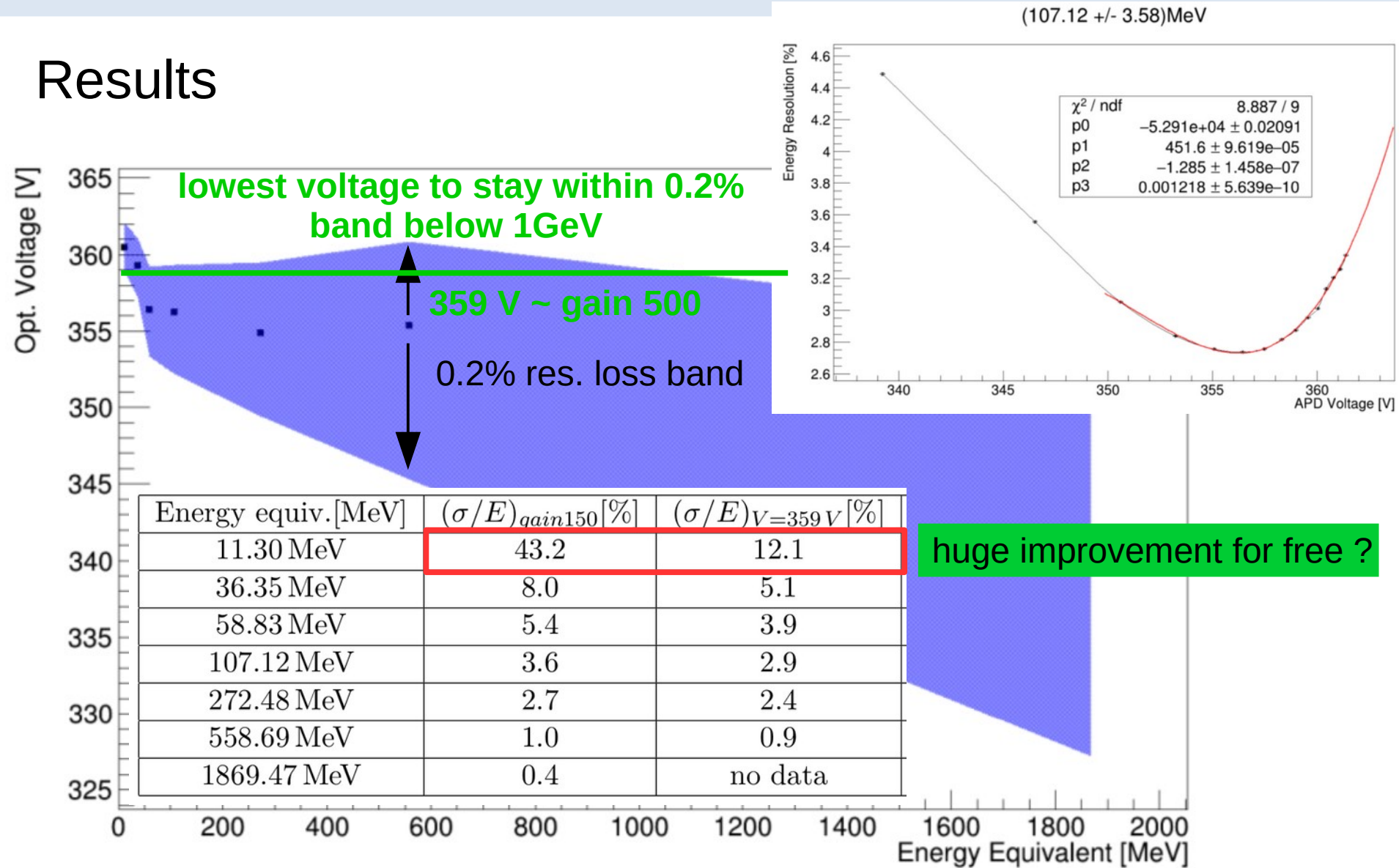


PANDA SADC with opt. feature extraction (Oliver Noll)

➔ very close to final PANDA setup

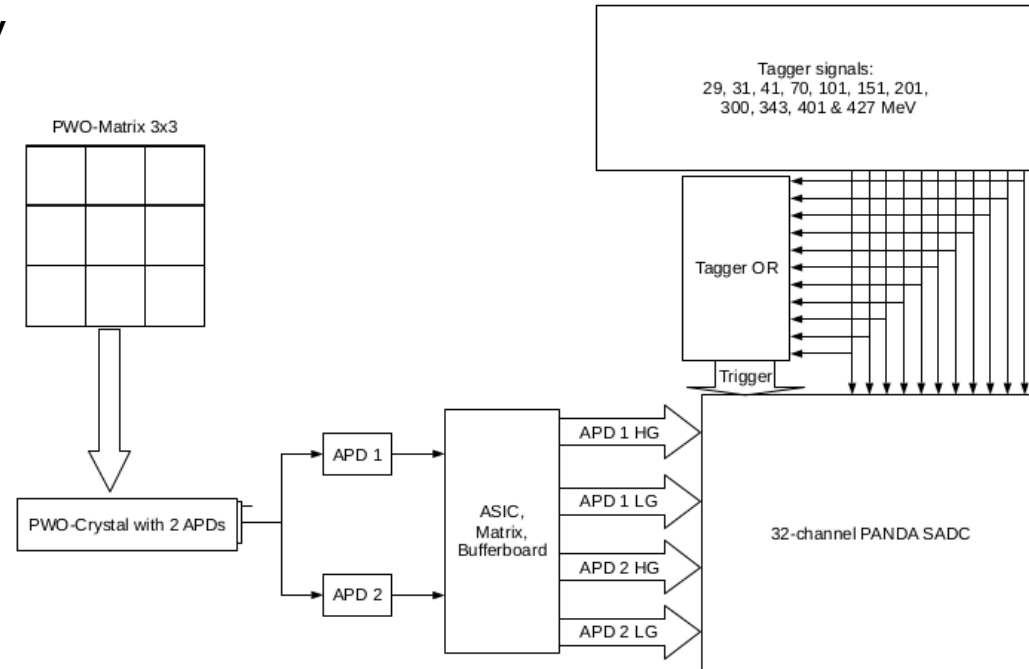
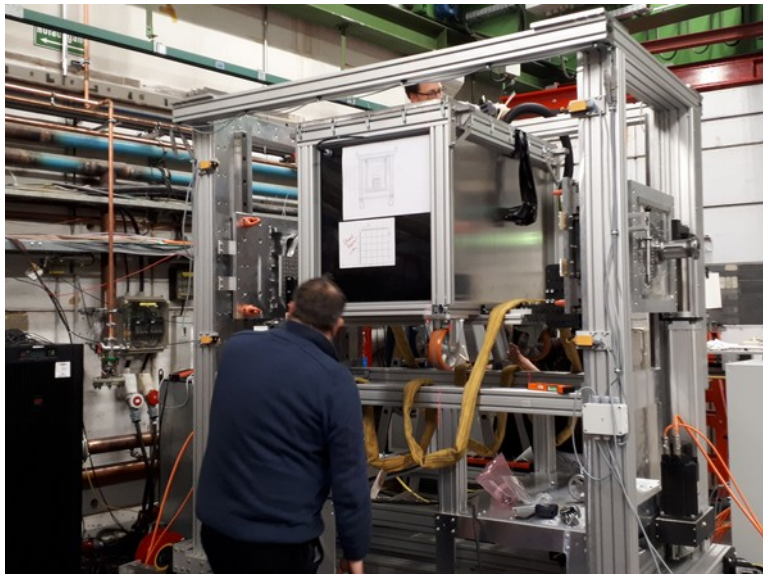
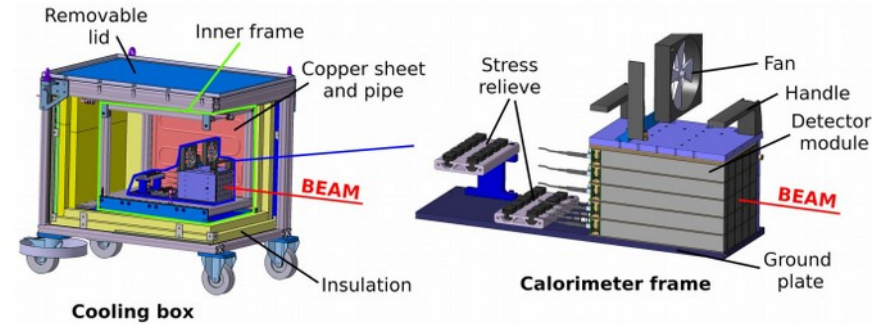
- Setup calibration with cosmic muons
- Light pulses from 11,3 MeV up to 1.9 GeV measured

Results



Setup

- 3x3 Matrix rectangular crystals @ -25°C
- 2 full screened & matched APDs per crystal
- Close to final read out
- Light Pulser
 - One fiber per Crystal
- Calib. reference in cooling box: fiber into APD with Basel preamp
- Tagged photons 29 MeV – 427 MeV



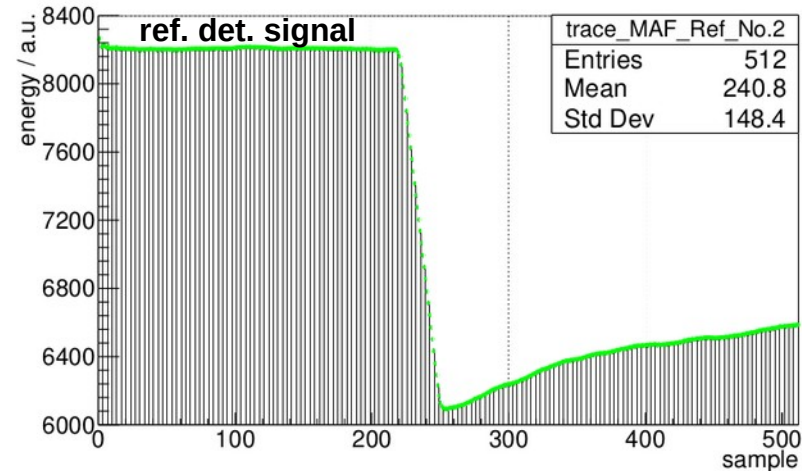
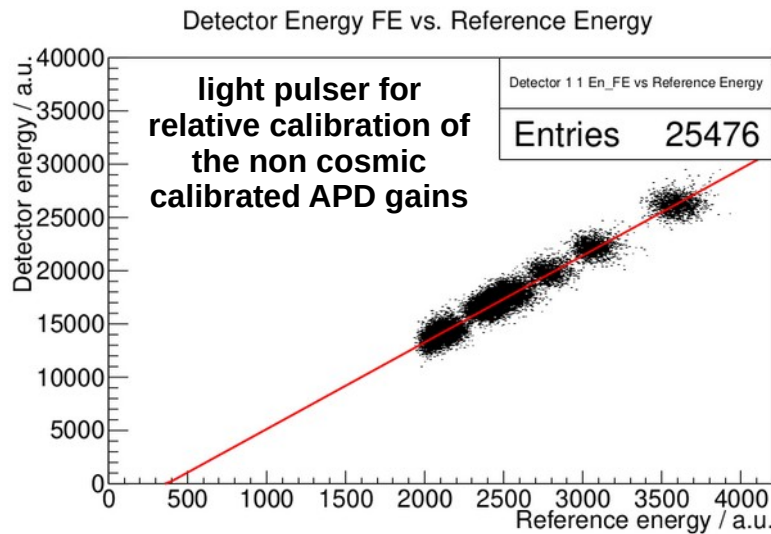
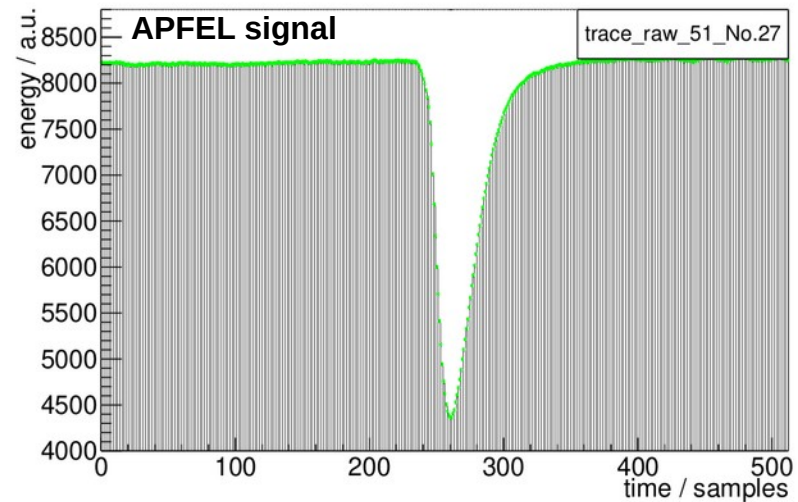
Procedure

- Limited amount of SADC channels → dedicate run for each APFEL setting
- Beam into the center
- SADCs raw data collected
 - FPGAs have not been used

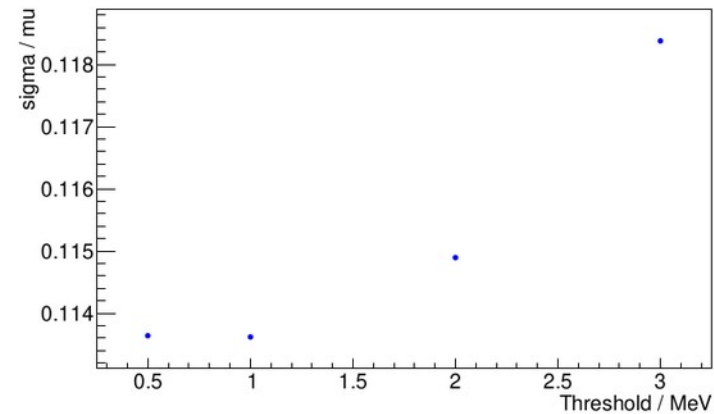
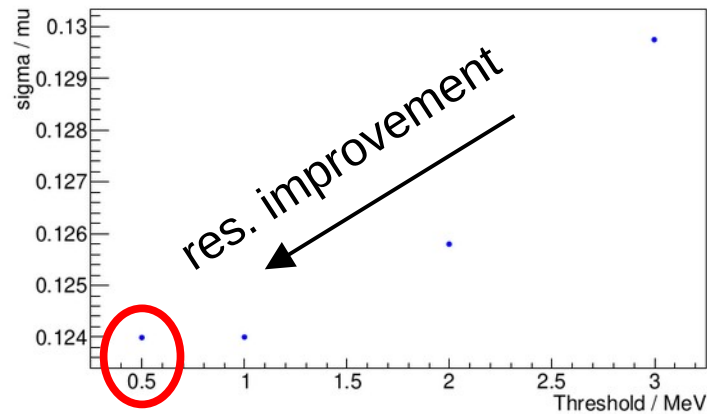
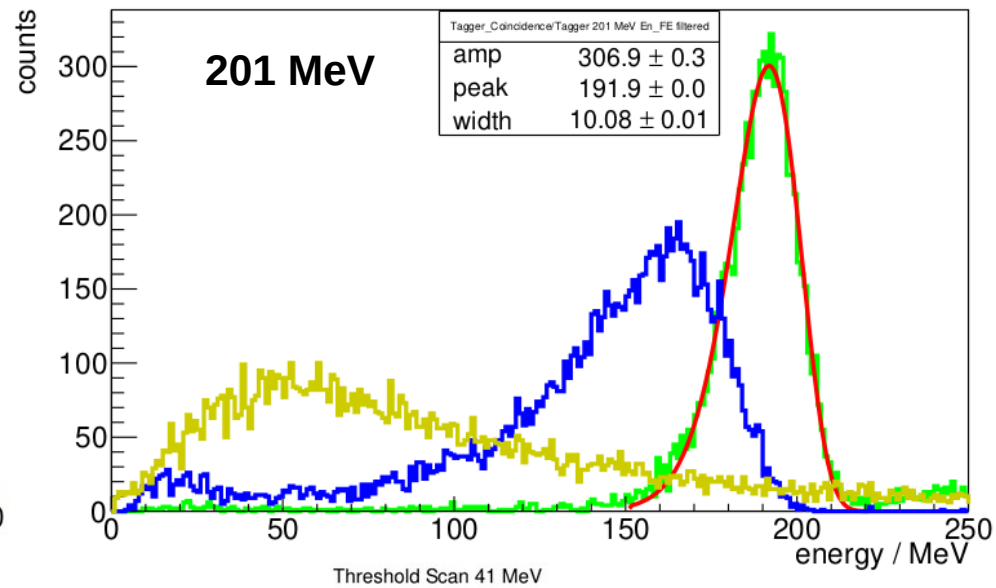
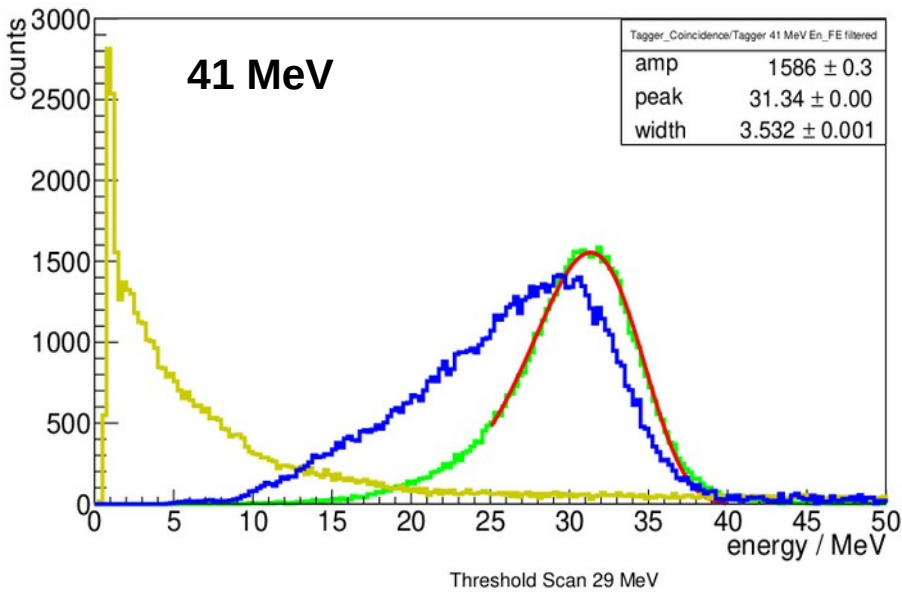
ASIC\APD	150	300	400	500
LG($\times 1$)	Beam&LP	Beam&LP	Beam&LP	Beam&LP
HG($\times 16$)	Beam&LP	Beam&LP	Beam&LP	Beam&LP
HG($\times 32$)	Beam&LP	Beam&LP	Beam&LP	Beam&LP
HG($\times 16$)				Cosmic

Analysis

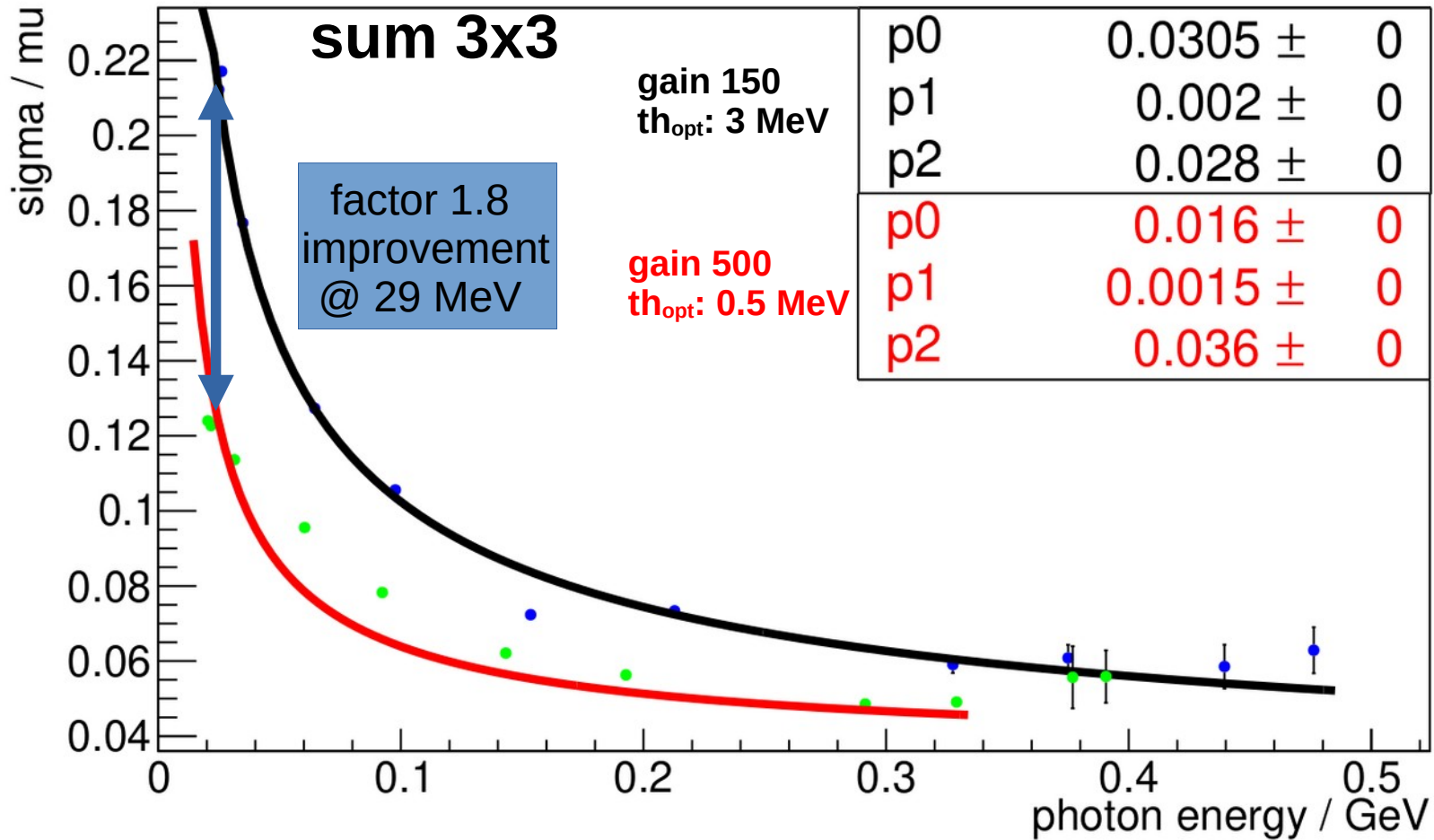
- Feature extraction:
 - APFEL signals: Oliver Nolls FE
 - Basel preamp: simple peak sensing algorithm
- Each APD threaded as individual detector
 - -> Individual calibration



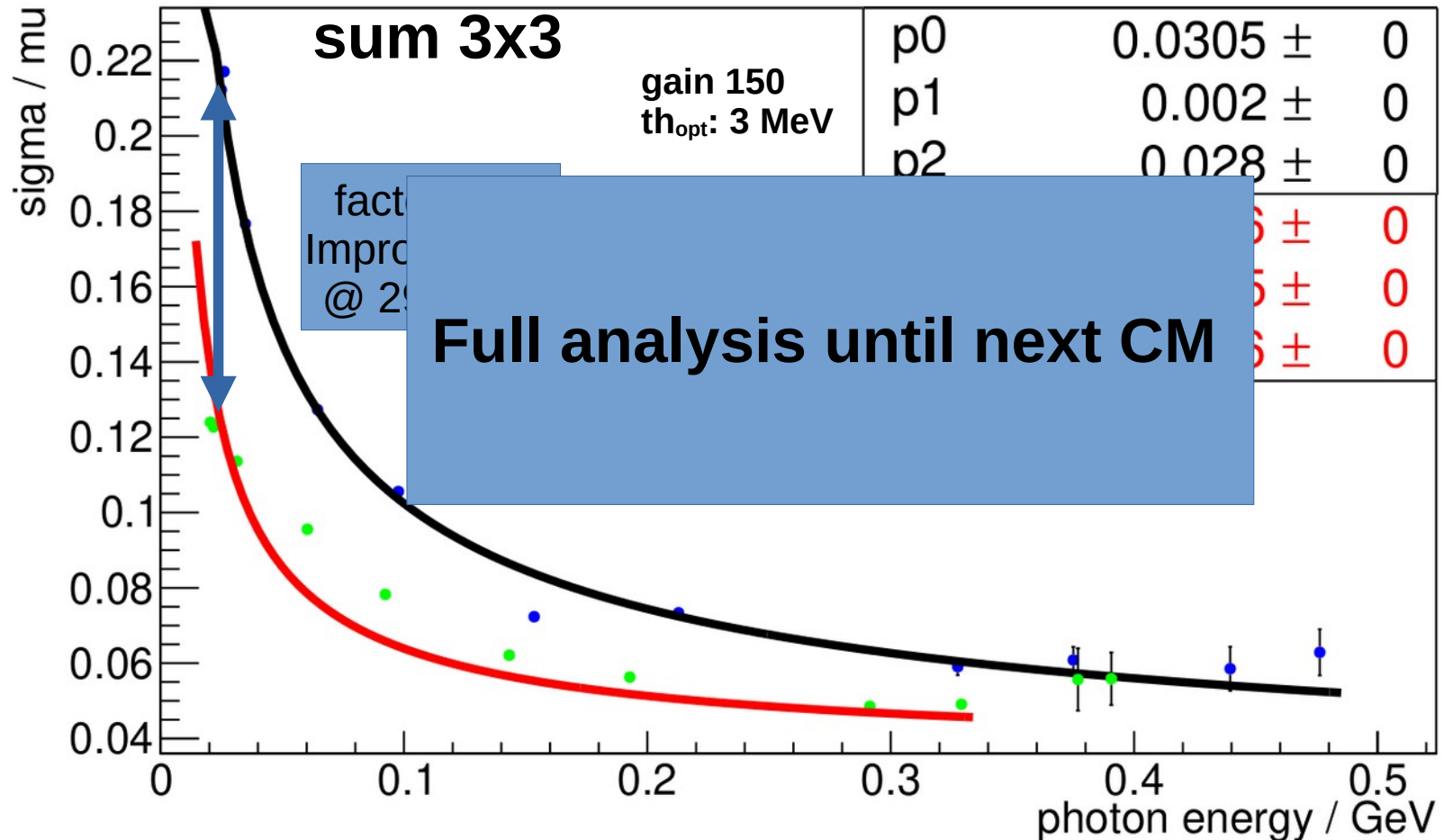
Analysis



Results



Results



SLice1			missed			SLice2			missed			SLice3			missed			SLice4			missed			SLice5			missed								
L	R		L	R		L	R		L	R		L	R		L	R		L	R		L	R		L	R		L	R							
1	0	0	1	0	0	1	0	0	1	0	0	1	0	0	1	0	0	1	0	0	1	0	0	1	0	0									
2	0	0	2	0	0	2	0	0	2	0	0	2	0	0	2	0	0	2	0	0	2	0	0	2	0	0									
3	0	0	3	0	0	3	0	0	3	41	0	3	41	0	3	41	0	3	41	0	3	41	0	3	41	0									
4	0	0	4	0	0	4	0	0	4	38	38	4	38	38	4	41	41	4	41	41	4	41	41	4	41	41									
5	0	0	5	0	0	5	0	0	5	39	37	5	39	37	5	41	41	5	41	41	5	41	41	5	41	41									
6	0	0	6	0	0	6	0	0	6	34	38	6	34	38	6	41	41	6	41	41	6	41	41	6	41	41									
7	0	0	7	0	0	7	0	0	7	41	40	7	41	40	7	41	41	7	41	41	7	41	41	7	41	41									
8	0	0	8	0	0	8	0	0	8	19	6	8	19	6	8	21	21	8	21	21	8	21	21	8	21	21									
9	0	0	9	0	0	9	0	0	9	0	0	9	0	0	9	0	0	9	0	0	9	0	0	9	0	0									
10	0	0	10	0	0	10	0	0	10	0	0	10	0	0	10	0	0	10	0	0	10	0	0	10	0	0									
11	0	0	11	0	0	11	0	0	11	0	0	11	0	0	11	0	0	11	0	0	11	0	0	11	0	0									
tot	0	0	tot	0	0	tot	0	0	tot	0	0	tot	0	0	tot	0	0	tot	0	0	tot	0	0	tot	0	0	tot	0	0	tot	0	0	tot	0	0
									371	212	159				411	226	185				411	226	185												

- Second slice Complete
- Production third slice ongoing

- Additional crystals needed for next slices
- Approx one spare crystal per type and slice

type	total	total+spare	To be ordered	
			Left	Right
1	1280	1310	0	0
2	1280	1310	219	0
3	1280	1310	519	0
4	1280	1310	572	572
5	1280	1310	573	571
6	1280	1310	568	572
7	1280	1310	575	574
8	640	660	288	275
9	640	660	0	0
10	640	660	212	28
11	480	490	80	110
total	11360	11640	3606	2702

full barrel: **6309**

- **Mechanics**
 - Remedy drawing pre-series slice Supportbeam ready
 - Company offer received
- **Fiber coupling monitor system**
 - CAD routing scheme almost finished
 - More crystals could get direct coupling when routing from up and downstream
- **APD gain**
 - Increased APD gain will significant improve resolution
 - Evaluation optimum value ongoing
- **HVD Backplane**
 - Final prototype ordered
 - Start mass production soon
- **Crystal production status**
 - Production 3rd slice ongoing

APD Gain Optimization for the APFEL ASIC

PWO-II LY @ +18°C: 20 PMT-phe/MeV
 PWO-II LY @ -25°C: 100 PMT-phe/MeV (LY@18°C X4)
 APD covers ~13% crystal endface
 PMT QE = 20%, LAAP QE= 80% → 52 APD-phe/MeV
 APFEL ASIC max Input: 8.5 pC

$$E_{max}(gain_{opt} 500) = \frac{8.5 \cdot 10^{-12} C}{52 \cdot 1.6 \cdot 10^{-19} C/MeV \cdot 500} = 2043.3 MeV$$

